Searcn Notes				

Application No.	Applicant(s)	
10/612,836	WEIMER ET AL.	
Examiner	Art Unit	
Stephen W. Smoot	2813	

SEARCHED			
Class	Subclass	Date	Examiner
438	301	9/16/2004	sws
438	303	9/16/2004	sws
438	595	9/16/2004	sws
438	786	9/16/2004	sws
438	791	9/16/2004	sws
427	255.29	9/16/2004	sws
427	255.39	9/16/2004	sws
427	255.393	9/16/2004	sws
427	255.394	9/16/2004	sws ,

INTERFERENCE SEARCHED				
Class	Subclass	Date	Examiner	

	SEARCH NOTES (INCLUDING SEARCH STRATEGY)			
	DATE	EXMR		
Key Words: Chemical Vapor Deposition -CVD, Tetrachlorosilane - TCS, Hexachlorodisilane - HCD;	9/16/2004	\$.U.\$ sws		
Deuterated Silicon Nitride - Spacer; Deuterated Silicon Oxynitride;	9/16/2004	S.W.S sws		
Anisotropic Etching - Gate Stack; lon Implantation - Source/Drain Regions; DRAM.	9/17/2004	I.W.S sws		
Search Tools - EAST (attached): USPAT; US PG PUBS; Derwent; EPO; JPO; IBM TDB	9/16/2004	LW S		